

## **NPN Silicon Transistor**

Symbol	Parameter	Value	Units
√ <sub>CBO</sub>	Collector-Base Voltage	700	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
/ <sub>EBO</sub>	Emitter- Base Voltage	9	V
с	Collector Current (DC)	8	A
CP	Collector Current (Pulse)	16	A
В	Base Current	4	A
°c	Collector Dissipation (T <sub>C</sub> =25°C)	80	W
Гј	Junction Temperature	150	°C
STG	Storage Temperature	- 65 ~ 150	°C

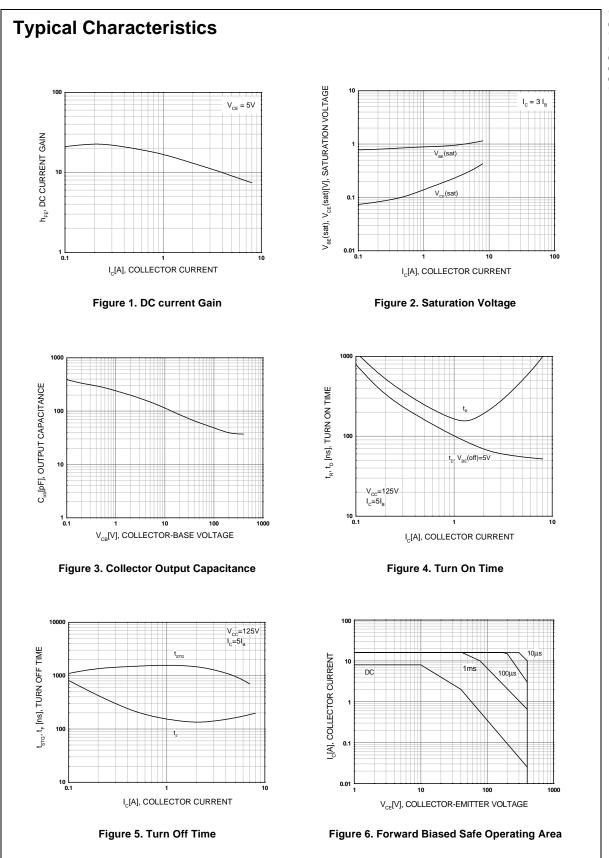
## Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector- Emitter Breakdown Voltage	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0	400			V
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$			1	mA
h <sub>FE1</sub>	*DC Current Gain	$V_{CE} = 5V, I_{C} = 2A$	8		60	
h <sub>FE2</sub>		$V_{CE} = 5V, I_{C} = 5A$	5		30	
V <sub>CE</sub> (sat)	*Collector-Emitter Saturation Voltage	$I_{\rm C} = 2A, I_{\rm B} = 0.4A$			1	V
		$I_{\rm C} = 5A, I_{\rm B} = 1A$	1.1	-7	2	V
		$I_{\rm C} = 8$ A, $I_{\rm B} = 2$ A	EE	373	3	V
V <sub>BE</sub> (sat)	*Base-Emitter Saturation Voltage	$I_{\rm C} = 2A, I_{\rm B} = 0.4A$	1.00	1 M W	1.2	V
		$I_{\rm C} = 5A, I_{\rm B} = 1A$			1.6	V
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 10V, f = 0.1MHz$		110		pF
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.5A$	4			MHz
t <sub>ON</sub>	Turn On Time	$V_{CC} = 125V, I_{C} = 5A$			1.6	μs
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = 1A$			3	μs
t <sub>F</sub>	Fall Time	$R_L = 50\Omega$			0.7	μs

<sup>\*</sup> Pulse test: PW≤300µs, Duty cycle≤2%

### h<sub>FE</sub> Classification

Classification	R(H1)	O(H2)		
h <sub>FE1</sub>	15 ~ 28	26 ~ 39		



## FJP13007

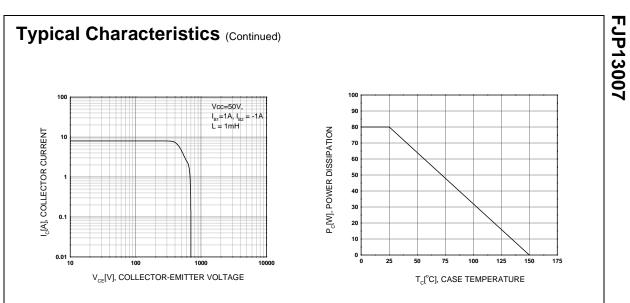
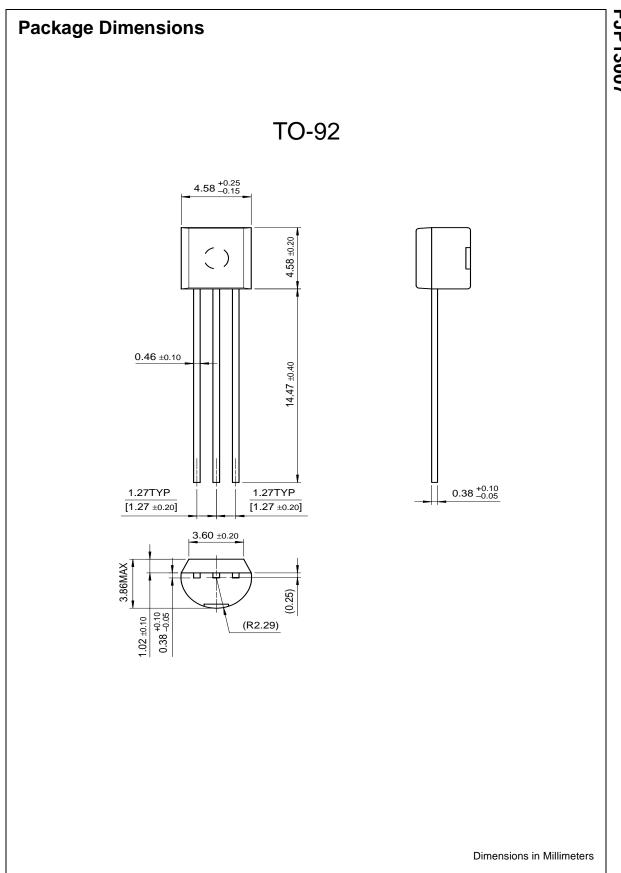


Figure 7. Reverse Biased Safe Ooperating Area

Figure 8. Power Derating



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